
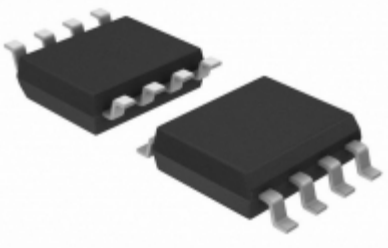
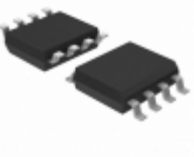
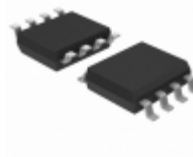
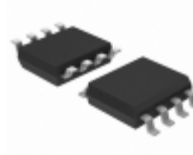

	<h2>SI4276DY-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI4276DY-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 30V 8A 8SO</p> <p>Datenblätter:  SI4276DY-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 17685 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI4276DY-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 30V 8A 8SO
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	17685 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	3.6W, 2.8W
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8A
Rds On (Max) @ Id, Vgs	15.3 mOhm @ 9.5A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	26nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1000pF @ 15V
Verpackung	Tape & Reel (TR)





































SI4276DY-T1-E3 ist neu im Original, Suche SI4276DY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4276DY-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4276DY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4230DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 8A 8SOIC</p>	 <p>SI4232DY. FAI SI4232DY. FAI</p>	 <p>SI4230DY-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 8A 8SOIC</p>	 <p>SI4276DY-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 8A 8-SOIC</p>
 <p>SI4282DVP VISHAY SI4282DVP VISHAY</p>	 <p>SI4276DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 8A 8-SOIC</p>	 <p>SI4276DY-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 8A 8SO</p>	 <p>SI4286DY VISHIAY SI4286DY VISHIAY</p>

heiße Teile

Mehr

 SI4210DY-T1-E3	 SI4210DY-T1-GE3	 SI4210DY-T1-GE3	 SI4210GM	 SI4214DDY
 SI4214DDY-T1-E3	 SI4214DDY-T1-E3	 SI4214DDY-T1-GE3	 SI4214DDY-T1-GE3	 SI4214DY-T1-E3
 SI4214DY-T1-GE3	 SI4214DY-T1-GE3	 SI4220-GM	 SI4226DY	 SI4226DY-T1-E3
 SI4226DY-T1-E3	 SI4226DY-T1-GE3	 SI4226DY-T1-GE3	 SI4228DY	 SI4228DY-T1-E3
 SI4228DY-T1-E3	 SI4228DY-T1-GE3	 SI4228DY-T1-GE3	 SI4232DY.	 SI4276DY-T1-E3
 SI4282DVP	 SI4286DY	 SI4286DY-T1-GE3	 SI4286DY-T1-GE3	 SI4288DY
 SI4288DY-T1-GE3	 SI4288DY-T1-GE3	 SI4300-BM	 SI4300-E-BM	 SI4300DY-T1-E3
 SI4308DY-T1	 SI4308DY-T1-E3	 SI4311-B21-GMR	 SI4320-J1-FTR	 SI4320DY
 SI4320DY-T1-E3	 SI4320DY-T1-E3	 SI4322-A0-FT	 SI4322-A0-FTR	 SI4322DY-T1-E3
 SI4322DY-T1-E3	 SI4324DY	 SI4324DY-T1-E3	 SI4324DY-T1-E3	 SI4326DY-T1-E3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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